Ordering number : ENN4228B

N-Channel Silicon MOSFET





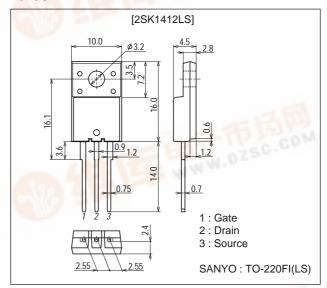
Ultrahigh-Speed Switching Applications

Features

- · Low ON-resistance, low input capacitance.
- · Ultrahigh-speed switching.
- · High reliability (Adoption of HVP process).
- Micaless package facilitating mounting.

Package Dimensions

unit : mm 2078C



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		1500	V
Gate-to-Source Voltage	VGSS		±20	٧
Drain Current (DC)	ID	4.26	0.1	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	0.2	Α
Allowable Power Dissipation	D=		2.0	W
	PD	Tc=25°C	20	W
Channel Temperature	Tch	L'al Car	150	°C
Storage Temperature	Tstg	C. CU.	-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _G S=0	1500			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =1200V, V _{GS} =0			100	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±20V, V _{DS} =0		100	±100	nA

(Note) Be careful in handling the 2SK1412LS because it has no protection diode between gate and source.

Continued on next page.

Marking: K1412

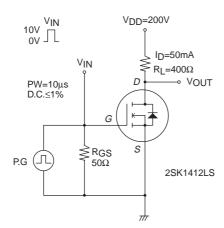
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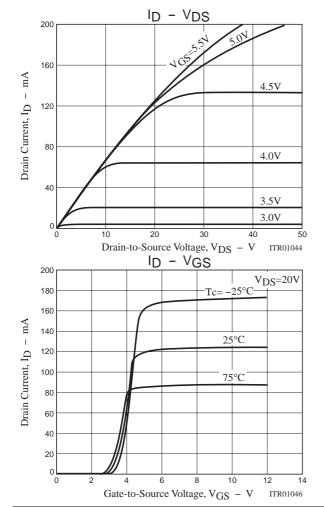
2SK1412LS

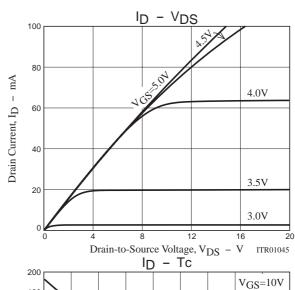
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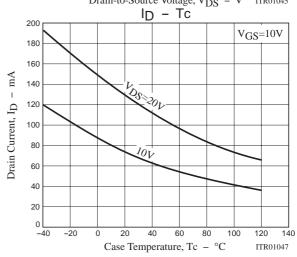
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Urill
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.5		3.5	V
Forward Transfer Admittance	yfs	V _{DS} =20V, I _D =50mA	50	100		mS
Static Drain-to-Source On-State Resistance	R _{DS} (on)	ID=50mA, VGS=10V		140	200	Ω
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		40		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		12		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		3.0		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit.		15		ns
Rise Time	t _r	See specified Test Circuit.		25		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		50		ns
Fall Time	tf	See specified Test Circuit.		350		ns
Diode Forward Voltage	V _{SD}	I _S =0.1A, V _G S=0		1.0	1.5	V

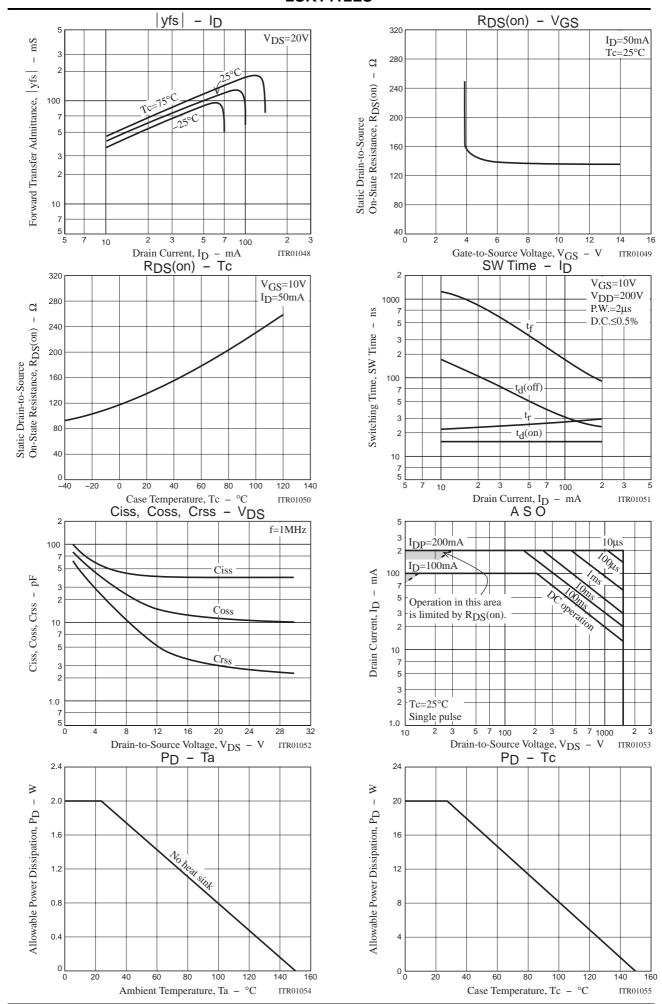
Switching Time Test Circuit











2SK1412LS

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